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**INFORMATION DISCLOSURE  
STATEMENT BY APPLICANT**

Sheet 1 of 1

Application #	10/689,841
Confirmation #	4232
Filing Date	10/22/2003
First Inventor	BRIOT
Art Unit	1765
Examiner	Unassigned Hiteshew
Docket #	P08025US01/RFH

**U.S. PATENT DOCUMENTS**

Exam. Initial*	Document No. Number - Kind	Publ. Date MM-DD-YYYY	Name Patentee or Applicant	Relevance Passages/Figs.
A F.H.	US-2003/0059971 A1	03-27-2003	Chua et al	—
	US-			
	US-			
	US-			
	US-			
	US-			
	US-			

**FOREIGN PATENT DOCUMENTS**

Exam. Initial*	DOCUMENT Country-Number-Kind	Publ. Date MM-DD-YYYY	Name Patentee or Applicant	Relevance Passages/Figs.	Translation
A F.H.	WO 00/07221	02-10-2000	Gilliland	—	—
A F.H.	EP 1 389 814 A2	02-18-2004	Matsuoka et al	—	—
A F.H.	JP 2000 315654 A	03-05-2001	Kazuo	—	Abstract
A F.H.	JP 2000 315653	03-05-2001	Kazuo	—	Abstract

**NON PATENT LITERATURE DOCUMENTS**

Exam. Initial*	Include NAME of the author (in CAPS), Title of Article/Item, Date, Page(s), Volume-Issue No., Publisher, City and/or Country where published	Translation
A F.H.	YUAN ET AL; "Electrically Driven Single-Photon Source"; Science; January, 2002, pp. 102-105; XP002278163	
X F.H.	BRIOT ET AL; "Indium nitride quantum dots grown by metalorganic vapor phase epitaxy"; Applied Physics Letters, American Institute of Physics; Vol. 83, No. 14; pp 2919-2921, XP001189952; October, 2003	
A F.H.	SCHALLENBERG ET AL; "Controlled self-assembly of semiconductor quantum dots using shadow masks"; Applied Physics Letters, American Institute of Physics; Vol. 82, No. 24; June, 2003; pp. 4349-4351; XP001175289	
A F.H.	WILLIAMS ET AL; "Controlling the self-assembly of InAs/InP quantum dots"; Journal of Crystal Growth; Vol. 223, No. 3, March, 2001; pp. 321-331; XP004229645	

Examiner Signature

*A. Hiteshew*

Date Considered

1/26/05

\* Examiner: Initial if considered, whether or not citation is in conformance with MPEP §609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.